

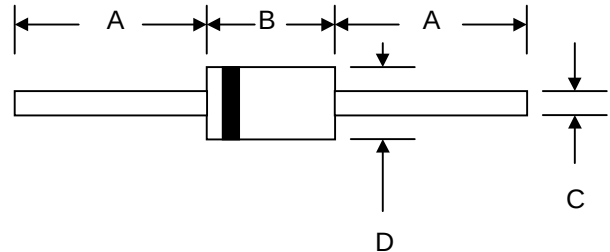
1.5A FAST RECOVERY RECTIFIER

FR151 - FR157

Vishaymas General Semiconductor

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability



Mechanical Data

Case: Molded Plastic

Terminals: Plated Leads Solderable
per MIL-STD-202, Method 208

Polarity: Cathode Band

Weight: 0.40 grams (approx.)

Mounting Position: Any

Marking: Type Number

DO-15		
Dim	Min	Max
A	25.4	—
B	5.50	7.62
C	0.71	0.864
D	2.60	3.60
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics

@T_A=25°C unless otherwise specified Single Phase, half wave, 60Hz,
resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	FR151	FR152	FR153	FR154	FR155	FR156	FR157	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T _A = 55°C	I _O	1.5							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	60							A
Forward Voltage @I _F = 1.5A	V _{FM}	1.2							V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	5.0 100							μA
Reverse Recovery Time (Note 2)	t _{rr}	150				250	500		nS
Typical Junction Capacitance (Note 3)	C _j	30							pF
Operating Temperature Range	T _j	-65 to +125							°C
Storage Temperature Range	T _{STG}	-65 to +150							°C

*Glass passivated forms are available upon request

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured with I_F = 0.5A, I_R = 1.0A, IRR = 0.25A. See figure 5.

3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

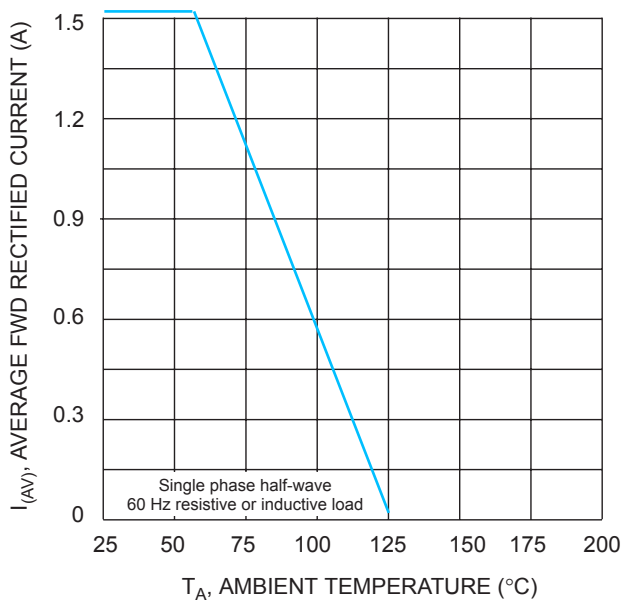


Fig. 1 Forward Derating Curve

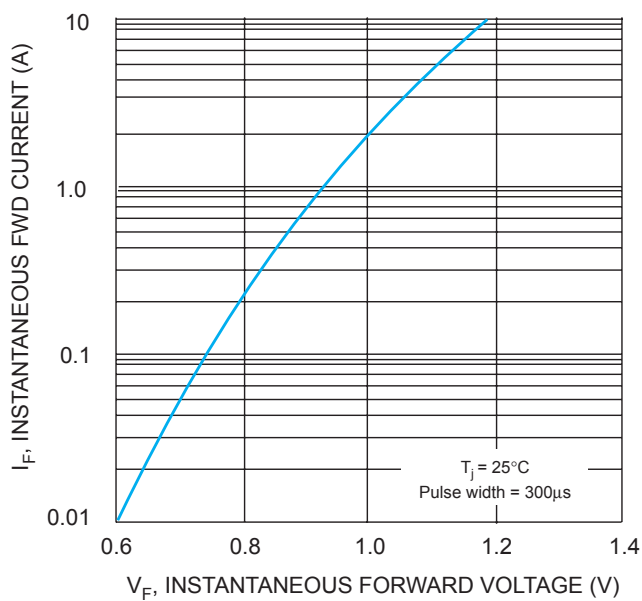


Fig. 2 Typical Forward Characteristics

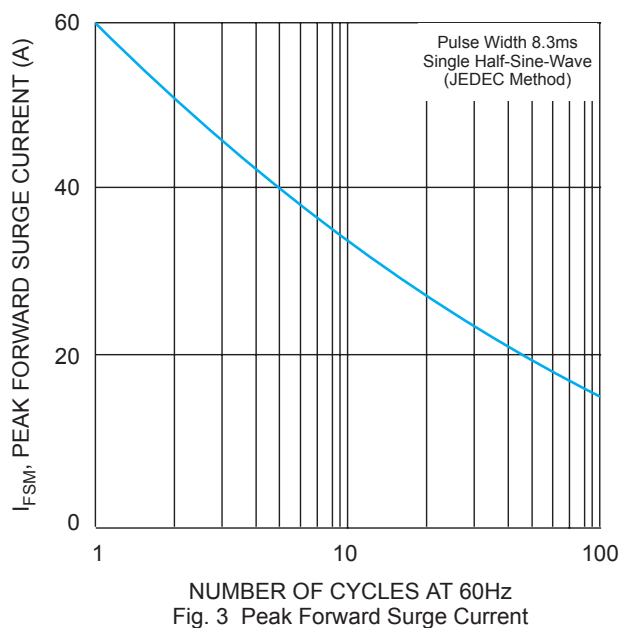


Fig. 3 Peak Forward Surge Current

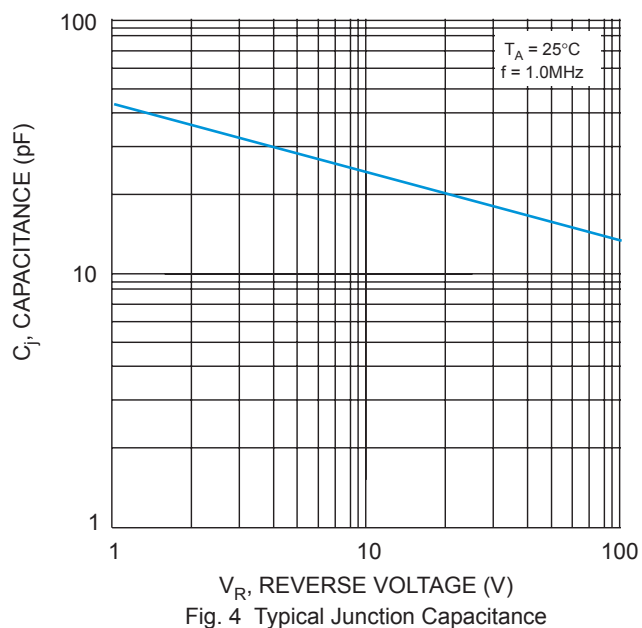
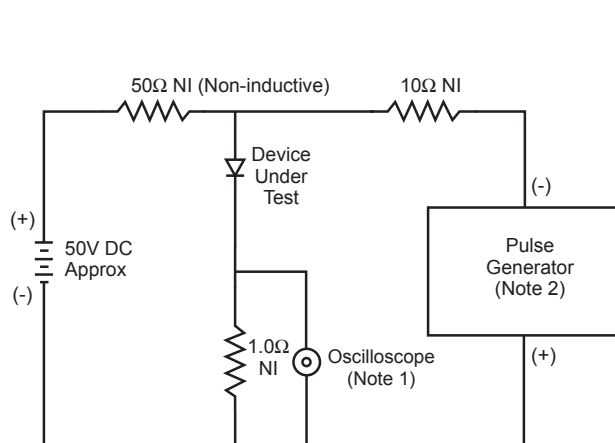
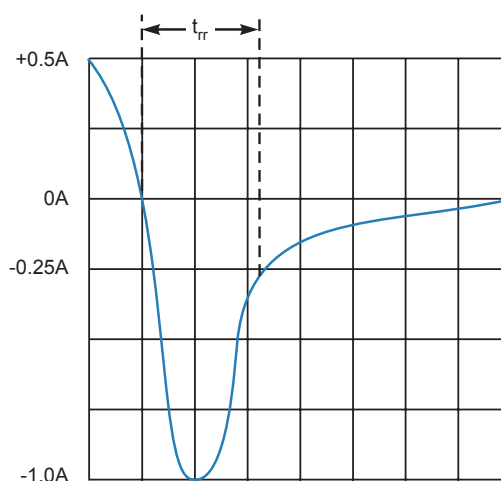


Fig. 4 Typical Junction Capacitance



Notes:

1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

